NSN 5961-00-780-8581

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-780-8581 **Inclosure Material:** Glass **Overall Length:** Between 0.200 inches and 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.290 inches and 0.390 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakover voltage, dc **Current Rating Per Characteristic:** 20.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnpn **Test Data Document:** 13499-353-3489 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No